35V N-CHANNEL ENHANCEMENT MODE MOSFET

SUMMARY

 $V(BR)DSS = 35V: RDS(on) = 0.060\Omega: ID = 13A$

DESCRIPTION

This new generation of high cell density planar MOSFETs from Zetex utilises a unique structure that combines the benefits of low on-resistance with fast switching speed. This makes them ideal for high efficiency, low voltage, power management applications.

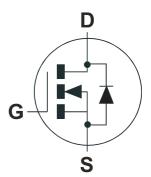
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FEATURES

- Low on-resistance
- Fast switching speed
- · Low threshold
- Low gate drive
- TO220 package

APPLICATIONS

- 100W Class D Audio Output Stage
- Motor Control

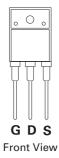


ORDERING INFORMATION

DEVICE	MULTIPLES				
ZXM64N035L3	1000				

DEVICE MARKING

ZXM6 4N035



ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	VDSS	35	V
Gate-Source Voltage	VGS	±20	V
Continuous Drain Current (VGS=10V; TC=25°C)(a) (VGS=10V; TA=25°C)(b)	ID	13 3.5	А
Pulsed Drain Current (b)	IDM	30	А
Continuous Source Current (Body Diode)(b)	IS	2.4	А
Pulsed Source Current (Body Diode)(b)	ISM	30	А
Power Dissipation at TA=25°C (a) Linear Derating Factor	PD	20 160	W mW/°C
Power Dissipation at TA=25°C (b) Linear Derating Factor	PD	1.5 12	W mW/°C
Operating and Storage Temperature Range	T _j :T _{stg}	-55 to +150	°C

THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT	
Junction to Case (a)	R_{θ} JC	6.25	°C/W	
Junction to Ambient (b)	R_{θ} JA	83.3	°C/W	



ELECTRICAL CHARACTERISTICS (at $T_A = 25^{\circ}C$ unless otherwise stated).

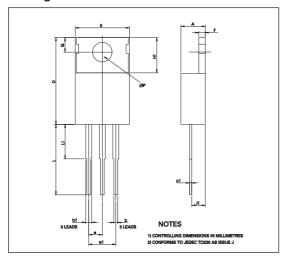
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.	
STATIC		•	•	•			
Drain-Source Breakdown Voltage	V(BR)DSS	35			V	I _D =250μA, V _G S=0V	
Zero Gate Voltage Drain Current	IDSS			1	μΑ	V _{DS} =35V, V _{GS} =0V	
Gate-Body Leakage	IGSS			100	nA	V _G S=±20V, V _D S=0V	
Gate-Source Threshold Voltage	VGS(th)	1.0			V	I _D =250μA, V _{DS} = V _{GS}	
Static Drain-Source On-State Resistance (1)	RDS(on)			0.060 0.070	Ω	V _{GS} =10V, I _D =3.7A V _{GS} =4.5V, I _D =1.9A	
Forward Transconductance (1)(3)	9fs	4.3			S	V _{DS} =10V,I _D =1.9A	
DYNAMIC (3)							
Input Capacitance	C _{iss}		950		pF		
Output Capacitance	Coss		200		pF	VDS=25V, VGS=0V, f=1MHz	
Reverse Transfer Capacitance	C _{rss}		50		pF]	
SWITCHING(2) (3)		•	•				
Turn-On Delay Time	^t d(on)		4.2		ns		
Rise Time	t _r		4.5		ns	V _{DD} =15V, I _D =3.7A	
Turn-Off Delay Time	td(off)		20.5		ns	RG=6.0Ω, VGS=10V	
Fall Time	tf		8		ns		
Total Gate Charge	Ωg			27	nC	VDS=24V,VGS=10V, I _D =3.7A	
Gate-Source Charge	Ogs			5	nC		
Gate-Drain Charge	Qgd			4.5	nC		
SOURCE-DRAIN DIODE	•						
Diode Forward Voltage (1)	V _{SD}			0.95	V	TJ=25°C, IS=3.7A, VGS=0V	
Reverse Recovery Time (3)	t _{rr}		24.5		ns	T _J =25°C, I _F =3.7A, di/dt= 100A/μs	
Reverse Recovery Charge (3)	Q _{rr}		19.1		nC		
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NOTES

- (1) Measured under pulsed conditions. Width=300 $\mu s.$ Duty cycle $\leq 2\%$.
- (2) Switching characteristics are independent of operating junction temperature.
- (3) For design aid only, not subject to production testing.



Package Outline



Package Dimensions

DIM	Millin	netres	Inches		
	Min		Min	Max	
Α	3.56	4.82	0.140	0.189	
b	0.38	1.01	0.015	0.040	
b1	1.15	1.77	0.045	0.070	
c1	1 0.41 0.50		0.016	0.020	
D	14.23	16.51	0.560	0.650	
E	9.66	10.66	0.380	0.419	
е	2.29	2.79	0.090	0.110	
e1	4.83	5.33	0.190	0.210	
F	0.51	1.39	0.20	0.055	
H1	11 5.58 6.85		0.230	0.270	
J1	2.04	2.92	0.080	0.115	
L	12.70	14.73	0.500	0.580	
L1	L1 — 6.35		_	0.250	
ØP	3.54	4.08	0.139	0.160	
Q	2.54 3.42		0.100	0.134	

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